

54ACT11240, 74ACT11240

Octal Buffers and Line Drivers With 3-State Outputs

These octal buffers and line drivers are designed specifically to improve both the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. These devices provide inverting outputs and symmetrical \overline{G} (active-low output control) inputs. These devices feature high fan-out and improved fan-in.

The 54ACT11240 is characterized for operation over the full military temperature range of -55°C to 125°C while the 74ACT11240 is characterized for operation from -40°C to 85°C.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

54ACT11240, 74ACT11240 OCTAL BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

T-52-07-00 T10072-D3410, MAY 1987-REVISED MARCH 1990

- Inputs are TTL-Voltage Compatible
- Flow-Through Architecture to Optimize PCB
- Center-Pin VCC and GND Configurations to Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-µm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil

description

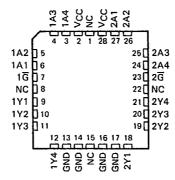
These octal buffers and line drivers are designed specifically to improve both the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. These devices provide inverting outputs and symmetrical G (active-low output control) inputs. These devices feature high fan-out and improved fan-

The 54ACT11240 is characterized for operation over the full military temperature range of -55°C to 125°C. The 74ACT11240 is characterized for operation from -40°C to

54ACT11240 ... JT PACKAGE 74ACT11240 ... DW OR NT PACKAGE (TOP VIEW)

1Y1 🛛	1	U 24	Ф	1G
1Y2 🗌	2	23	30	1A1
1Y3 🗌	3	23	2[]	1A2
1Y4 🗌	4	2	ıD	1A3
GND 🗌	5	20	叩	1A4
GND 🗌	6	19	₽□	Vcc
GND 🗌	7	18	_	Vcc
GND 🗌	8	1	7	2A1
2Y1 🗀	9	10	6	2A2
2Y2 🗌	10	1	5	2A3
2Y3 🗌	11	14	4[2A4
2Y4 🗌	12	1:	3 [2G

54ACT11240 ... FK PACKAGE (TOP VIEW)



NC-No internal connection

FUNCTION TABLE (each gate)

INP	UTS	OUTPUT
G	Α	Y
L	Н	L
L	L	н
Ιн	Х	z

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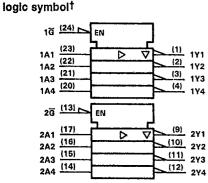
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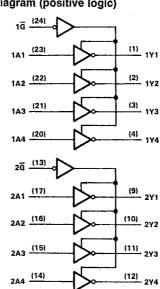
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TI0072-D3410, MAY 1987--REVISED MARCH 1990logic diagram (positive logic)



[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for DW, JT, and NT packages.



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, VCC			-0.5	V to 7 V
Input voltage range, V _i (see Note 1)	-0.5	V to	Vcc	+ 0.5 V
Output voltage range, VO (see Note 1)	-0.5	V to	Voc	+ 0.5 V
Input clamp current, IfK (VI < 0 or VI > VCC)				±20 mA
Output clamp current, IOK (VO < 0 or VO > VCC)				±50 mA
Continuous output current, IO ($VO = 0$ to VCO)				±50 mA
Continuous current through VCC or GND pins			. ±	200 mA
Storage temperature range		-6	35°C	to 150°C

^{\$} Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

		54	ACT112	40	74ACT11240		40	T
		MiN	NOM	MAX	MiN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			v
VIL	Low-level input voltage			0.8			0.8	v
Vj	Input voltage	0		Vcc	0	·	Vcc	v
۷o	Output voltage	0	·	VCC	0		VCC	v
ЮН	High-level output current	····		-24			-24	mA
OL	Low-level output current			24			24	mA
Δt/Δv	Input transition rise or fall rate	0		10	0		10	ns/V
TA	Operating free-air temperature	-55		125	-40		85	°C



54ACT11240, 74ACT11240 OCTAL BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	TECT COMPLETIONS		T/	= 25°C	54ACT	11240	74ACT1	1240	
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP MAX	MIN	MAX	MIN	MAX	UNIT
		4.5 V	4.4		4.4		4.4		
	$l_{OH} = -50 \mu A$	5.5 V	5.4		5.4		5.4		
Voн		4.5 V	3.94		3.7		3.8		v
	IOH = -24 mA	5.5 V	4.94		4.7		4.8		٧
	IOH = -50 mA†	5.5 V			3.85				
	IOH = -75 mA†	5,5 V					3.85		
•	1 504	4.5 V		0.1		0.1		0.1	
	IOL = 50 μA	5.5 V		0.1		0.1		0.1	
14	1	4.5 V		0.36	1	0,5		0.44	v
VOL	IOL = 24 mA	5.5 V	1	0,36	T	0.5		0.44	V
	IOL = 50 mA†	5.5 V	T			1.65			
	IOL = 75 mAt	5.5 V						1.65	-
loz	VO = VCC or GND	5.5 V		±0.5		±10		±5	μΑ
li .	V ₁ = V _{CC} or GND	5.5 V		±0.1		±1		±1	μΑ
lcc	VI = VCC or GND, IO = 0	5.5 V		8		160		80	μA
Alest	One input at 3.4 V,	5.5 V		0.9		-		1	mA
ΔlCC‡	Other inputs at GND or VCC	9.0 Y		0.9		'			IIIA
Ci	VI = VCC or GND	5 V		4					ρF
Co	Vo = Vcc or GND	5 V		10					ρF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ (see Figure 1)

B40411777	FROM	TO	TA	1 = 25°	C	54ACT	11240	74ACT	11240	
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
tPLH			1.5	6.5	9.9	1.5	11.1	1.5	10.6	
tpHL	Α	, T	1.5	6	. 8	1.5	9.2	1.5	8.7	ns
tpzH	G	, , , , , , , , , , , , , , , , , , ,	1.5	7.5	11.7	1.5	13.1	1.5	12.5	
tpzL	G	*	1.5	7.3	11.5	1.5	12.8	1.5	12.3	ns
tPHZ	G	, , , , , , , , , , , , , , , , , , ,	1.5	7.3	9.4	1,5	10,3	1.5	10	
tPLZ.	. u	1	1.5	7,9	10.3	1.5	11.2	1.5	10.8	ns

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

ſ		PARAMETER		TEST CONDITIONS	TYP	UNIT
ſ	<u>~ .</u>	Davies disclarities considered and sale	Outputs enabled	0: - 50-5 4 - 4 1415-	47	-1"
١	Cpd	Power dissipation capacitance per gate	Outputs disabled	C _L = 50 pF, f = 1 MHz	13	рF



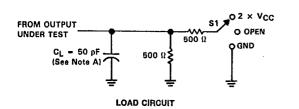
^{*} This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

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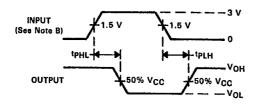
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PARAMETER MEASUREMENT INFORMATION

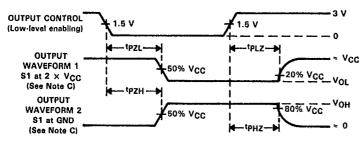
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OPEN
× Vcc
GND



PROPAGATION DELAY TIMES



ENABLE AND DISABLE TIMES

- NOTES: A. C_L includes probe and jig capacitance.
 B. Input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω, t_f = 3 ns, t_f = 3 ns.
 C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with Internal conditions such that the output is high except when disabled by the output control.
 - D. The outputs are measured one at a time with one transition per measurement.

FIGURE 1. LOAD CIRCUIT AND VOLTAGE WAVEFORMS



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